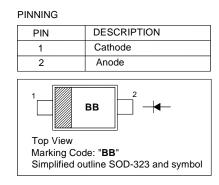
SD188SBWS

SILICON SCHOTTKY BARRIER DIODE

Features

- Small surface mounting type
- \bullet Ultra low V_{F}
- High reliability



Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V _{RM}	20	V
Reverse Voltage	V _R	10	V
Mean Rectifying Current	Ι _ο	200	mA
Peak Forward Surge Current	I _{FSM}	0.5	А
Junction Temperature	Tj	125	°C
Storage Temperature Range	Ts	- 40 to + 125	°C

Characteristics at T_a = 25 °C

W

	Parameter	Symbol	Max.	Unit
www.[Forward Voltage at $I_F = 50 \text{ mA}$ at $I_{E} = 200 \text{ mA}$	V _F	0.3 0.41	V
	Reverse Current at $V_R = 10 V$	I _R	20	μA

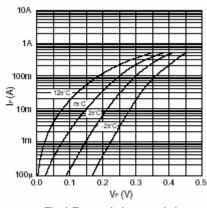
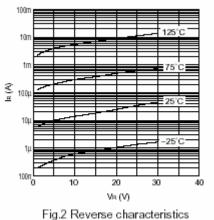


Fig.1 Forward characteristics



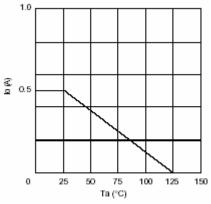


Fig.3 Derating curve



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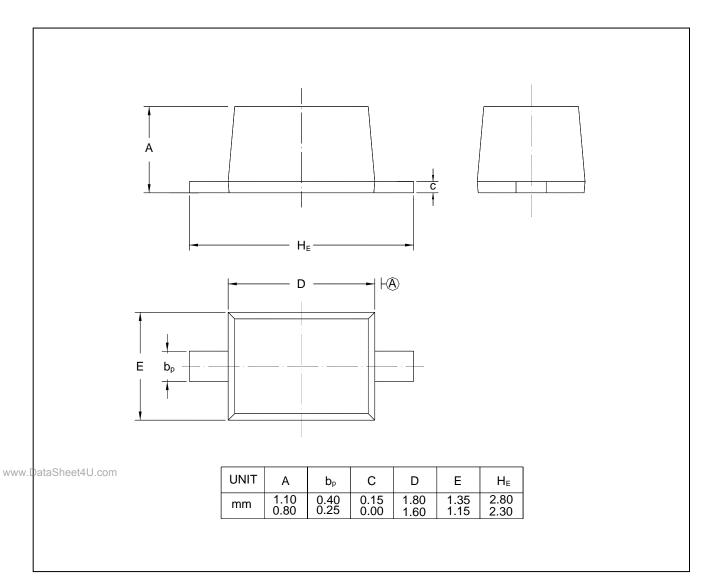


Dated : 01/09/2006

SOD-323

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads





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